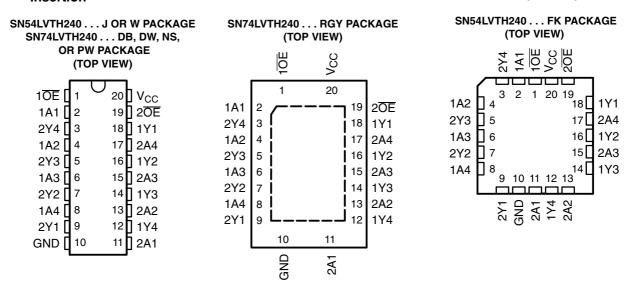
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- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V<sub>CC</sub>)
- Support Unregulated Battery Operation Down to 2.7 V
- Typical V<sub>OLP</sub> (Output Ground Bounce)
   <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- I<sub>off</sub> and Power-Up 3-State Support Hot Insertion
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)



### description/ordering information

These octal buffers and line drivers are designed specifically for low-voltage (3.3-V)  $V_{CC}$  operation, but with the capability to provide a TTL interface to a 5-V system environment.

#### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAGE <sup>†</sup>	†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RGY	Tape and reel	SN74LVTH240RGYR	LXH240
-40°C to 85°C	COIC DW	Tube	SN74LVTH240DW	LVTUO40
	SOIC – DW	Tape and reel	SN74LVTH240DWR	LVTH240
	SOP - NS	Tape and reel	SN74LVTH240NSR	LVTH240
	SSOP – DB	Tape and reel	SN74LVTH240DBR	LXH240
	TOOOD DW	Tube	SN74LVTH240PW	1.7/1040
	TSSOP – PW	Tape and reel	SN74LVTH240PWR	LXH240
	VFBGA – GQN	Town and well	SN74LVTH240GQNR	1.7/1040
	VFBGA – ZQN (Pb-free)	Tape and reel	SN74LVTH240ZQNR	LXH240
	CDIP – J	Tube	SNJ54LVTH240J	SNJ54LVTH240J
-55°C to 125°C	CFP – W	Tube	SNJ54LVTH240W	SNJ54LVTH240W
	LCCC - FK	Tube	SNJ54LVTH240FK	SNJ54LVTH240FK

<sup>&</sup>lt;sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



## SN54LVTH240, SN74LVTH240 3.3-V ABT OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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#### description/ordering information (continued)

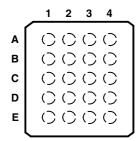
These devices are organized as two 4-bit buffer/line drivers with separate output-enable ( $\overline{OE}$ ) inputs. When  $\overline{OE}$  is low, the devices pass data from the A inputs to the Y outputs. When  $\overline{OE}$  is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

These devices are fully specified for hot-insertion applications using  $I_{off}$  and power-up 3-state. The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

# SN74LVTH240 . . . GQN OR ZQN PACKAGE (TOP VIEW)



### terminal assignments

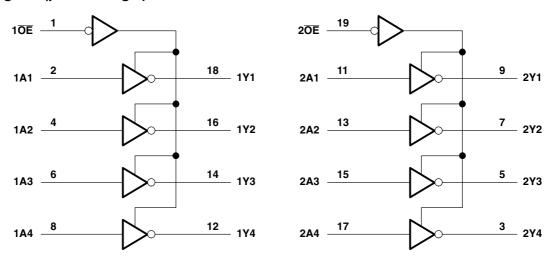
	1	2	3	4
Α	1A1	1 <del>OE</del>	$V_{CC}$	2 <del>0E</del>
В	1A2	2A4	2Y4	1Y1
С	1A3	2Y3	2A3	1Y2
D	1A4	2A2	2Y2	1Y3
E	GND	2Y1	2A1	1Y4

# FUNCTION TABLE (each 4-bit buffer)

INPL	JTS	OUTPUT
OE	Α	Y
L	Н	L
L	L	Н
Н	Χ	Z



#### logic diagram (positive logic)



Pin numbers shown are for the DB, DW, FK, J, NS, PW, RGY, and W packages.

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	-0.5 V to 4.6 V
nput voltage range, V <sub>I</sub> (see Note 1)	
Voltage range applied to any output in the high-impedance	
or power-off state, V <sub>O</sub> (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state, VO (see Note 1)0.5 V	
Current into any output in the low state, IO: SN54LVTH240	96 mA
SN74LVTH240	128 mA
Current into any output in the high state, IO (see Note 2): SN54LVTH240	48 mA
SN74LVTH240	64 mA
nput clamp current, $I_{IK}$ ( $V_I < 0$ )	–50 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	–50 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 3): DB package	70°C/W
(see Note 3): DW package	58°C/W
(see Note 3): GQN/ZQN package	78°C/W
(see Note 3): NS package	
(see Note 3): PW package	83°C/W
(see Note 4): RGY package	37°C/W
Storage temperature range, T <sub>stg</sub> –	65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
  - 2. This current flows only when the output is in the high state and  $V_O > V_{CC}$ .
  - 3. The package thermal impedance is calculated in accordance with JESD 51-7.
  - 4. The package thermal impedance is calculated in accordance with JESD 51-5.



# SN54LVTH240, SN74LVTH240 3.3-V ABT OCTAL BUFFERS/DRIVERS **WITH 3-STATE OUTPUTS**

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#### recommended operating conditions (see Note 5)

			SN54LV	TH240	SN74LV	TH240	UNIT
			MIN	MAX	MIN	MAX	UNII
V <sub>CC</sub>	Supply voltage		2.7	3.6	2.7	3.6	V
V <sub>IH</sub>	High-level input voltage		2		2		V
V <sub>IL</sub>	Low-level input voltage			0.8		8.0	V
VI	Input voltage		5.5		5.5	V	
I <sub>OH</sub>	High-level output current			-24		-32	mA
l <sub>OL</sub>	Low-level output current			48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
Δt/ΔV <sub>CC</sub>	Power-up ramp rate		200		200		μs/V
T <sub>A</sub>	Operating free-air temperature		-55	125	-40	85	°C

NOTE 5: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETER		7507.001	IDITIONS	SN54	LVTH24	0	SN74	LVTH240	)	
PA	RAMETER	TEST CO	NUTTIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
$V_{IK}$		$V_{CC} = 2.7 \text{ V},$	$I_I = -18 \text{ mA}$			-1.2			-1.2	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	$I_{OH} = -100  \mu A$	V <sub>CC</sub> -0.2			V <sub>CC</sub> -0.2			
V		$V_{CC} = 2.7 \text{ V},$	$I_{OH} = -8 \text{ mA}$	2.4			2.4			V
$V_{OH}$		V 0V	$I_{OH} = -24 \text{ mA}$	2						V
		V <sub>CC</sub> = 3 V	$I_{OH} = -32 \text{ mA}$				2			
		V 07V	$I_{OL} = 100 \mu\text{A}$			0.2			0.2	
		V <sub>CC</sub> = 2.7 V	I <sub>OL</sub> = 24 mA			0.5			0.5	
.,			I <sub>OL</sub> = 16 mA			0.4			0.4	V
$V_{OL}$		V <sub>CC</sub> = 3 V	$I_{OL} = 32 \text{ mA}$			0.5			0.5	V
		v <sub>CC</sub> = 3 v	$I_{OL} = 48 \text{ mA}$			0.55				
			$I_{OL} = 64 \text{ mA}$						0.55	
	Control inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V <sub>I</sub> = 5.5 V			10			10	
	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1	^
I <sub>I</sub>	Data innuta	V 26V	$V_I = V_{CC}$			1			1	μΑ
	Data inputs	$V_{CC} = 3.6 \text{ V}$	V <sub>I</sub> = 0			-5			-5	
$I_{\rm off}$		$V_{CC} = 0$ , $V_{I}$ or $V_{O} = 0$ to 4.5 V							±100	μΑ
		V <sub>CC</sub> = 3 V	V <sub>I</sub> = 0.8 V	75			75			
I <sub>I(hold)</sub>	Data inputs		V <sub>I</sub> = 2 V	-75			-75			μ <b>A</b>
·i(iioia)	Jana III paro	$V_{CC} = 3.6 V^{\ddagger},$	$V_{I} = 0 \text{ to } 3.6 \text{ V}$						500 -750	μ
$I_{OZH}$		$V_{CC} = 3.6 \text{ V},$	V <sub>O</sub> = 3 V			5			5	μΑ
I <sub>OZL</sub>		$V_{CC} = 3.6 \text{ V},$	V <sub>O</sub> = 0.5 V			-5			-5	μΑ
I <sub>OZPU</sub>		$V_{CC} = 0$ to 1.5 V, $V_{O} = \overline{OE} = \text{don't care}$	0.5 V to 3 V,			±100*			±100	μА
I <sub>OZPD</sub>		$V_{CC} = 1.5 \text{ V to } 0, V_{O} = \overline{OE} = \text{don't care}$	0.5 V to 3 V,			±100*			±100	μΑ
		$V_{CC} = 3.6 \text{ V},$	Outputs high			0.19			0.19	
I <sub>CC</sub>	$I_{CC}$ $I_{O} = 0$ ,		Outputs low			5			5	mA
	$V_I = V_{CC}$ or GND	Outputs disabled			0.19			0.19		
Δl <sub>CC</sub> §	$\begin{array}{c} V_{CC} = 3 \text{ V to } 3.6 \text{ V,} \\ \text{One input at } V_{CC} - 0.6 \\ \text{Other inputs at } V_{CC} \text{ or} \end{array}$					0.2			0.2	mA
C <sub>i</sub>		V <sub>I</sub> = 3 V or 0			3			3		pF
Co		$V_O = 3 V \text{ or } 0$			7			7		pF

 $<sup>\</sup>ast$  On products compliant to MIL-PRF-38535, this parameter is not production tested.



<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

<sup>&</sup>lt;sup>‡</sup> This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

<sup>§</sup> This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V<sub>CC</sub> or GND.

## **SN54LVTH240, SN74LVTH240** 3.3-V ABT OCTAL BUFFERS/DRIVERS **WITH 3-STATE OUTPUTS**

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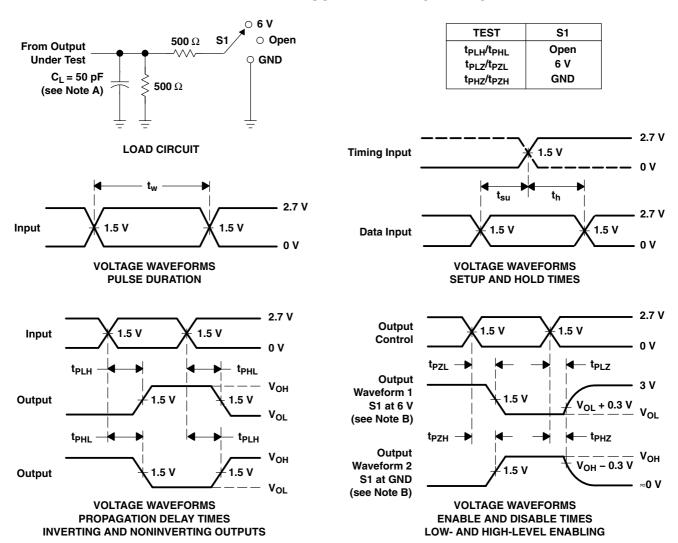
## switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

				SN54L\	/TH240			SN7	4LVTH2	240			
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}$ = 3.3 V $\pm$ 0.3 V		V <sub>CC</sub> = 2.7 V		$V_{CC}$ = 3.3 V $\pm$ 0.3 V			V <sub>CC</sub> = 2.7 V		UNIT	
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN	MAX		
t <sub>PLH</sub>	۸	Υ	0.9	4.3		5.1	1.1	2.2	3.8		4.6	20	
t <sub>PHL</sub>	А	Ť	1.2	4.7		4.9	1.3	2.6	4		4.2	ns	
t <sub>PZH</sub>	ŌĒ	Y	1	5.7		6.7	1.1	2.6	4.6		5.6	20	
t <sub>PZL</sub>	ÖE	Ť	1.2	5.5		6.2	1.4	2.7	4.4		5	ns	
t <sub>PHZ</sub>	OF.	ŌĒ	, , , , , , , , , , , , , , , , , , ,	1	5.1		5.2	2	2.9	4.4		4.6	20
t <sub>PLZ</sub>	OE	Υ	1.1	5.4		5.4	1.8	3	4.3		4.3	ns	

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .



#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{Q}$  = 50  $\Omega$ ,  $t_{f} \leq$  2.5 ns.  $t_{f} \leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

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#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9950801Q2A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9950801Q2A SNJ54LVTH 240FK	Samples
5962-9950801QRA	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9950801QR A SNJ54LVTH240J	Samples
5962-9950801QSA	ACTIVE	CFP	W	20	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9950801QS A SNJ54LVTH240W	Samples
SN74LVTH240DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH240	Samples
SN74LVTH240DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH240	Samples
SN74LVTH240DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH240	Samples
SN74LVTH240DWRE4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH240	Samples
SN74LVTH240NSR	ACTIVE	SOP	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH240	Samples
SN74LVTH240PW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH240	Samples
SN74LVTH240PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH240	Samples
SNJ54LVTH240FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9950801Q2A SNJ54LVTH 240FK	Samples
SNJ54LVTH240J	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9950801QR A SNJ54LVTH240J	Samples
SNJ54LVTH240W	ACTIVE	CFP	W	20	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9950801QS A SNJ54LVTH240W	Samples

<sup>(1)</sup> The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

## PACKAGE OPTION ADDENDUM

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NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN54LVTH240, SN74LVTH240:

Catalog: SN74LVTH240

Military: SN54LVTH240

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

## **PACKAGE OPTION ADDENDUM**

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• Military - QML certified for Military and Defense Applications

## **PACKAGE MATERIALS INFORMATION**

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#### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH240DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVTH240DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LVTH240NSR	so	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LVTH240PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



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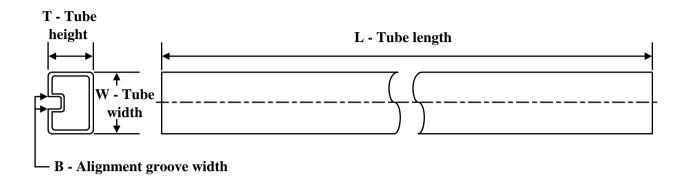
#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH240DBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74LVTH240DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVTH240NSR	so	NS	20	2000	367.0	367.0	45.0
SN74LVTH240PWR	TSSOP	PW	20	2000	356.0	356.0	35.0

## **PACKAGE MATERIALS INFORMATION**

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#### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9950801Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
SN74LVTH240DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74LVTH240PW	PW	TSSOP	20	70	530	10.2	3600	3.5
SNJ54LVTH240FK	FK	LCCC	20	55	506.98	12.06	2030	NA





- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



#### **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

## 14-PINS SHOWN

#### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



## 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## W (R-GDFP-F20)

## CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

  D. Index point is provided on cap for terminal identification only.

  E. Falls within Mil—Std 1835 GDFP2—F20







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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